

## PCN# 20210625000.1 Qualification of new Fab site (RFAB) using qualified Process Technology, Die Revision, Datasheet update and additional Assembly site/BOM options for select devices Change Notification / Sample Request

Date: June 29, 2021 To: TOKYO ELECTRON DEVICE (DSTR) PCN

Dear Customer:

This is an announcement of a change to a device that is currently offered by Texas Instruments (TI). The details of this change are on the following pages, and are in alignment with our standard product change notification (PCN) <u>process</u>.

TI requires acknowledgement of receipt of this notification within 30 days of the date of this notice. Lack of acknowledgement of this notice within 30 days constitutes acceptance of the change. If samples or additional data are required, requests must be received within 30 days of this notification, given that samples are not built ahead of the change.

The Proposed First Ship date in this PCN letter is the earliest possible date that customers could receive the changed material. It is our commitment that the changed device will not ship before that date. If samples are requested within the 30 day sample request window, customers will still have 30-days to complete their evaluation regardless of the proposed 1st ship date.

This particular PCN is related to TI's previous announcement to close our two remaining factories with 150-millimeter production (DFAB in Dallas, Texas, and SFAB in Sherman, Texas). As referenced in the "reason for change" below, these changes are part of our multiyear plan to transition these products to newer, more efficient manufacturing processes and technologies, underscoring our commitment to product longevity and supply continuity.

For questions regarding this notice or to provide acknowledgement of this PCN, you may contact your local Field Sales Representative or the PCN Team (<u>PCN ww admin team@list.ti.com</u>). For sample requests or sample related questions, contact your local Field Sales Representative. As always, we thank you for your continued business.

PCN Team SC Business Services

## **Products Affected:**

The devices listed on this page are a subset of the complete list of affected devices. According to our records, these are the devices that you have purchased within the past twenty-four (24) months. The corresponding customer part number is also listed, if available.

DEVICE	CUSTOMER PART NUMBER
MAX3232CDR	null
MAX3232CPWR	null
MAX3232EIPWR	null
TRS3232EIPWR	null
MAX3232IPWR	null
TRSF3232ECPWR	null
MAX3232ECDBR	null
MAX3232ECPWR	null
MAX3232EIDBR	null
SN65C3232PWR	null
SN65C3232EPWR	null
SN65C3232EDBR	null
MAX3232CPWRG4	null
MAX3232IDBR	null
SN75C3232EPWR	null
TRS3232ECPWR	null
MAX3232IPWRG4	null
MAX3232EIDR	null

Technical details of this Product Change follow on the next page(s).

PCN Number: 20210625000.1			25000.1		PC	N Da	ate:	June 29, 2021		
Title:Qualification of new Fab site (RFAB) using quad Datasheet update and additional Assembly sit										
Cus	tomer	Contact:		PCI	<u>N Manager</u>		De	ept:		Quality Services
Proposed 1 <sup>st</sup> Ship Date:			Sep 29, 2021 Estima Availat					Date provided at sample request.		
Cha	Change Type:									· · · ·
$\boxtimes$	Assem	bly Site			Assembly Process			$\boxtimes$	Asser	mbly Materials
$\boxtimes$	Desigr	า		Electrical Specification		ation			Mech	anical Specification
	Test Site Packing/Shippin		Packing/Shipping/	Labeling	J		Test I	Process		
Wafer Bump Site Wafer Bump Materi		rial			Wafe	r Bump Process				
$\boxtimes$	Wafer	Fab Site		Wafer Fab Materials			$\boxtimes$	Wafe	r Fab Process	
	Part number change									
PCN Details										

## **PCN Details**

## **Description of Change:**

Texas Instruments is pleased to announce the qualification of a new fab & process technology (RFAB, LBC7) and assembly (MLA) site/BOM options for selected devices as listed below in the product affected section.

	Current Fa	b Site	New Fab Site			
Fab Site	Fab Site         Process         Wafer Diameter			Process	Wafer Diameter	
DL-LIN	LBC3S	150 mm				
DL-LIN	LBC3S	200 mm	RFAB	LBC7	300 mm	
CFAB	LBC3S	200 mm				

The die was also changed as a result of the process change.

The datasheets will be changing as a result of the above mentioned changes. The datasheet change details can be reviewed in the datasheet revision history. The link to the revised datasheet is available in the table below.

Texas Instruments	TRS3232E SLLS790D – JUNE 2007 – REVISED JUNE 2021
Changes from Revision C (June 2021) to Revision D (June 2021)	Page
<ul> <li>Added Applications: Industrial PCs, Wired networking, and Data of Changed the table note in the ESD Ratings - IEC Specifications to packages.</li> </ul>	o make it applicable to D, DB and PW
Changed the thermal paramater values for D, DB and PW package	
Texas Instruments	TRSF3232E SLL S825B - AUGUST 2007 - REVISED JUNE 2021

SLLS825B - AUGUST 2007 - REVISED JUNE 2021

Page

## Changes from Revision A (December 2020) to Revision B (June 2021)

Added Applications: Industrial PCs, Wired networking, and Data center and enterprise computing......1

- Changed the table note in the ESD Protection, Driver table to make it applicable to D and PW packages......4 Changed the table note in the ESD Protection, Reciever table to make it applicable to D and PW packages....
- Changed the thermal parameter values for D and PW packages in the Thermal Information table......5

# Changes from Revision D (May 2017) to Revision E (June 2021)

- Added Applications: Industrial PCs, Wired networking, and Data center and enterprise computing......1
- Added the ESD Ratings IEC Specifications table. Added a table note about 1-uF capacitor requirement
- Changed the thermal parameter values for D, DB and PW packages in the Thermal Information table......5

# Changes from Revision A (July 2015) to Revision B (June 2021)

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MAX3232 SLLS4100 - JANUARY 2000 - REVISED JUNE 2021

SLLS812B - JULY 2007 - REVISED JUNE 2021

## Changes from Revision N (June 2017) to Revision O (June 2021)

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- Added Applications: Industrial PCs, Wired networking, and Data center and enterprise computing......1
- TEXAS INSTRUMENTS

SLLS540C - JULY 2002 - REVISED JUNE 2021

Ĵ	nanges from Revision B (November 2004) to Revision C (June 2021)	Page
	Added Device Information table, Pin Configuration and Functions section, ESD Ratings table, Feature	
	Description section, Device Functional Modes, Application and Implementation section, Power Supply	
	Recommendations section, Layout section, Device and Documentation Support section, and Mechanica	al,
	Packaging, and Orderable Information section	1
	Added Applications: Industrial PCs, Wired networking, and Data center and enterprise computing	1
	Added thermal parameter values for all packages and changed the thermal parameters for D package i	n the
	Thermal Information table	5

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Ų	Texas Instruments	SN65C3232E, SN75C3232 SLLS897B – DECEMBER 2005 – REVISED JUNE 202	
Char	nges from Revision A (December 2007) to Revision B (June 2021)	Page	
Fe Si M	dded Device Information table, Pin Configuration and Functions section eature Description section, Device Functional Modes, Application and upply Recommendations section, Layout section, Device and Docume lechanical, Packaging, and Orderable Information section pdated the list of Applications	Implementation section, Power entation Support section, and 1	
• A sp • A	dded a note specifying a minimum capacitor of 1 $\mu$ F between V <sub>CC</sub> and becifications in the <i>ESD Protection, Driver</i> table dded a note specifying the need for a 1- $\mu$ F capacitor between V <sub>CC</sub> an becifications in the <i>ESD Protection, Receiver</i> table	I GND to satisfy IEC ESD 4 d GND to satisfy IEC ESD	



MAX3232E

**TRS3232** 

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Page

#### SN65C3232, SN75C3232

Product Folder	Current Datasheet Number	New Datasheet Number	Link to full datasheet
TRS3232E	SLLS790C	SLLS790D	http://www.ti.com/product/TRS3232E
TRSF3232E	SLLS825A	SLLS825B	http://www.ti.com/product/TRSF3232E
MAX3232E	SLLS664D	SLLS664E	http://www.ti.com/product/MAX3232E
TRS3232	SLLS812A	SLLS812B	http://www.ti.com/product/TRS3232
MAX3232	SLLS410N	SLLS4100	http://www.ti.com/product/MAX323
SN65C3232 SN75C3232	SLLS540B	SLLS540C	http://www.ti.com/product/SN65C3232
SN65C3232E, SN75C3232E	SLLS697A	SLLS697B	http://www.ti.com/product/SN65C3232E

Construction differences are noted below:

## **Group 1 MLA A/T site & BOM updates for D Devices:**

	ASESH	FMX	MLA – New Site
Mount compound	EY1000063	4147858	4147858
	(EN-4900GC)	(QMI 505MT)	(QMI 505MT)
Mold Compound	EN2000506	4211880	4211880
	(CEL-9240HF-10AK)	(EME-G633C)	(EME-G633C)
Lead finish	Matte Sn	NiPdAu	NiPdAu

## **Group 2 MLA A/T site & BOM updates for PW Devices:**

	ASESH	MLA – New Site
Mount compound	EY1000063 (EN-4900GC)	4147858 (QMI 505MT)
Mold Compound	EN2000506 (CEL-9240HF-10AK)	4211471 (EME-G610TA)
Lead Finish	Matte Sn	NiPdAu

Tube versions of the devices are included in EOL notice PDN# 20210625001.3

Qual details are provided in the Qual Data Section.

## **Reason for Change:**

These changes are part of our multiyear plan to transition products from our 150-milimeter factories to newer, more efficient manufacturing processes and technologies, underscoring our commitment to product longevity and supply continuity.

# Anticipated impact on Form, Fit, Function, Quality or Reliability (positive / negative):

None

## **Anticipated impact on Material Declaration**

	No Impact to the Material		Material Declarations or Product Content reports are driven from production data and will be available following the production
	Declaration		release. Upon production release the revised reports can be obtained from the <u>TI ECO website</u> .
Changes to product identification resulting from this PCN:			

Changes to product identification resulting from this PCN:

## Fab Site Information:

Chip Site	Chip Site Origin Code (20L)	Chip Site Country Code (21L)	Chip Site City
DL-LIN	DLN	USA	Dallas
CFAB	CU3	CHN	Chengdu
RFAB – New Fab	RFB	USA	<b>Richardson</b>

# Die Rev:

Product Family	Current	New
	Die Rev [2P]	Die Rev [2P]
MAX3232C, MAX3232I, TRS3232I	D	В
MAX3232E, SN65C3232E, SN75C3232E, TRS3232E	F	В
SN65C3232	В	В

## **Assembly Site Information:**

Assembly Site	Assembly Site Origin (22L)	Assembly Country Code (23L)	Assembly City
ASESH	ASH	CHN	Shanghai
TI Mexico	MEX	MEX	Aguascalientes
TI Malaysia	MLA	MYS	Kuala Lumpur

Sample product shipping label (not actual product label)



Group 1 - RFAB/Process migration, Die Rev, Datasheet, MLA A/T site & BOM updates for D Devices:									
MAX3232CDR	SN65C3232DR	SN75C3232DR	SN75C3232DRE4						

PW Devices: MAX3232CPWR

(3232CPWR	MAX3232IPWR
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Group 3 - RFAB/Process migration, Die Rev & Datasheet changes:											
MAX3232CDBR	MAX3232EIDBRE4	SN65C3232EDBRG4	TRS3232EIDBR								
MAX3232CDBRE4	MAX3232EIDR	SN65C3232EDR	TRS3232EIDR								
MAX3232CPWRE4	MAX3232EIPWR	SN65C3232EDRG4	TRS3232EIPWR								
MAX3232CPWRG4	MAX3232EIPWRG4	SN65C3232EPWR	TRS3232EIPWRG4								
MAX3232ECDBR	MAX3232IDBR	SN65C3232PWR	TRS3232IPWR								
MAX3232ECDR	MAX3232IDBRE4	SN65C3232PWRE4	TRSF3232ECDR								

MAX3232ECDRE4	MAX3232IPWRE4	SN75C3232EPWR	TRSF3232ECPWR	
MAX3232ECPWR	MAX3232IPWRG4	TRS3232ECDR	TRSF3232EIDR	
MAX3232EIDBR	SN65C3232EDBR	TRS3232ECPWR	TRSF3232EIPWR	

## Group 1 & 3 Qual Memo:

#### Qualification Report

#### Approve Date 01-Jun-2021

#### Qualification Results Data Displayed as: Number of lots / Total sample size / Total failed

	Data Displayed as. Number of 10137 Total Sample Size 7 Total Taned											
Туре	Test Name / Condition	Duration	Qual Device: <u>TR \$3232EIDR</u>	QBS Product Reference: <u>TRS3232EIPW (PG2.0)</u>	QBS Process Reference: <u>TPS51217DSC</u>	QBS Process Reference: <u>TP \$53605D SQ</u>	QBS Package Reference: <u>ULQ2003AQDRQ1</u>					
AC	Autoclave 121C	96 Hours	-	-	3/231/0	-	3/231/0					
CDM	ESD - CDM	1500 V	1/3/0	-	-	-	-					
ED	Electrical Characterization	Per Datasheet Parameters	Pass	Pass	-	-	-					
ELFR	Early Life Failure Rate, 125C	48 Hours	-	-	-	3/2999/0	-					
HAST	Biased HAST 130C/85%RH	96 Hours	-	-	3/231/0	-	3/231/0					
HAST	Biased HAST, 110C/85%RH	264 Hours	-	-	-	3/231/0	-					
HBM	ESD - HBM (All Pins)	4000 V	-	3/9/0	-	-	-					
HBM	ESD - HBM (Bus Pins)	16000 V	-	3/9/0	-	-	-					
HTOL	Life Test, 125C	1000 Hours	-	3/231/0	-	3/231/0	3/231/0					
HTOL	Life Test, 135C	635 Hours	-	-	3/231/0	-	-					
HTSL	High Temp Storage Bake 150C	1000 Hours	-	-	-	-	3/135/0					
HTSL	High Temp Storage Bake 170C	420 Hours	-	-	3/231/0	2/90/0	-					
LU	Latch-up	(Per JESD78)	-	1/6/0	-	-	-					
тс	Temperature Cycle - 65/150C	500 Cycles	-	-	3/231/0	3/231/0	3/231/0					
UHAST	Unbiased HAST 110C/85%RH	264 Hours	-	-	-	3/231/0	-					
WBP	Bond Pull	Wires	1/76/0	1/76/0	-	3/228/0	-					
WBS	Ball Bond Shear	Wires	1/76/0	1/76/0	-	3/228/0	-					

- QBS: Qual By Similarity

- Qual Device TRS3232EIDR is qualified at LEVEL1-260C

- Preconditioning was performed for Autoclave, Unbiased HAST, THB/Biased HAST, Temperature Cycle, Thermal Shock, and HTSL, as applicable

- The following are equivalent HTOL options based on an activation energy of 0.7eV: 125C/1k Hours, 140C/480 Hours, 150C/300 Hours, and 155C/240 Hours

- The following are equivalent HTSL options based on an activation energy of 0.7eV: 150C/1k Hours, and 170C/420 Hours

- The following are equivalent Temp Cycle options per JESD47: -55C/125C/700 Cycles and -65C/150C/500 Cycles

Quality and Environmental data is available at TI's external Web site: http://www.ti.com/

Green/Pb-free Status:

## Group 1 & 3 Qual Memo:

#### Qualification Report

#### Approve Date 03-Jun-2021

#### Qualification Results

#### Data Displayed as: Number of lots / Total sample size / Total failed

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Туре	Test Name / Condition	Duration	Qual Device: <u>TRSF3232EIDR</u>	QBS Product Reference: <u>TRSF3232EIPWR</u>	QBS Product Reference: <u>TRSF3232EIRGT</u>	QBS Process Reference: <u>TPS51217DSC</u>	QBS Process Reference: <u>TPS53605DSQ</u>	QBS Package Reference: <u>ULQ2003AQDRQ1</u>			
AC	Autoclave 121C	96 Hours	-	-	-	3/231/0	-	3/231/0			
CDM	ESD - CDM	1500 V	1/3/0	-	-	-	-	-			
ED	Electrical Characterization	Per Datasheet Parameters	Pass	Pass	Pass	-	-	-			
ELFR	Early Life Failure Rate, 125C	48 Hours	-	-	-	-	3/2999/0	-			
HAST	Biased HAST, 110C/85%RH	264 Hours	-	-	-	-	3/231/0	-			
HAST	Biased HAST, 130C/85%RH	96 Hours	-	-	-	3/231/0	-	3/231/0			
HBM	ESD - HBM (All Pins)	4000 V	-	1/3/0	-	-	-	-			
HBM	ESD - HBM (Bus Pins)	16000 V	-	1/3/0	-	-	-	-			
HTOL	Life Test, 125C	1000 Hours	-	-	-	-	3/231/0	3/231/0			
HTOL	Life Test, 135C	635 Hours	-	-	-	3/231/0	-	-			
HTSL	High Temp Storage Bake 150C	1000 Hours	-	-	-	-	-	3/135/0			
HTSL	High Temp Storage Bake, 170C	420 Hours	-	-	-	3/231/0	2/90/0	-			
LU	Latch-up	(per JESD78)	-	-	1/6/0	-	-	-			
тс	Temperature Cycle, - 65/150C	500 Cycles	-	-	-	3/231/0	3/231/0	3/231/0			
UHAST	Unbiased HAST 110C/85%RH	264 Hours	-	-	-	-	3/231/0	-			
WBP	Bond Pull	Wires	1/76/0	1/76/0	1/76/0	-	3/228/0	-			

Туре	Test Name / Condition	Duration	Qual Device: TRSF3232EIDR	QBS Product Reference: <u>TRSF3232EIPWR</u>	QBS Product Reference: <u>TRSF3232EIRGT</u>	QBS Process Reference: <u>TPS51217DSC</u>	QBS Process Reference: <u>TPS53605DSQ</u>	QBS Package Reference: <u>ULQ2003AQDRQ1</u>
WBS	Ball Bond Shear	Wires	1/76/0	1/76/0	1/76/0	-	3/228/0	-

- QBS: Qual By Similarity

- Qual Device TRSF3232EIDR is qualified at LEVEL1-260C

- Preconditioning was performed for Autoclave, Unbiased HAST, THB/Biased HAST, Temperature Cycle, Thermal Shock, and HTSL, as applicable

The following are equivalent HTOL options based on an activation energy of 0.7eV: 125C/1k Hours, 140C/480 Hours, 150C/300 Hours, and 155C/240 Hours
 The following are equivalent HTSL options based on an activation energy of 0.7eV: 150C/1k Hours, and 170C/420 Hours
 The following are equivalent HTSL options based on an activation energy of 0.7eV: 150C/1k Hours, and 170C/420 Hours
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 The following are equivalent HTSL options based on an activation energy of 0.7eV: 150C/1k Hours, and 170C/420 Hours
 The following are equivalent HTSL options based on an activation energy of 0.7eV: 150C/1k Hours, and 170C/420 Hours
 Hours
 Hours and Environmental data is available at TI's external Web site: http://www.ti.com/
 Green/Pb-free Status:
 Qualified Pb-Free (SMT) and Green

## Group 2 & 3 Qual Memo:

# Qualification Report Approved Date 14-Dec-2020

#### Qualification Results

#### Data Displayed as: Number of lots / Total sample size / Total failed

Data Displayed as: Number of lots / Total sample size / Total failed										
Туре	Test Name / Condition	Duration	Qual Device: <u>TR\$3232EIPW</u> <u>(PG2.0)</u>	QBS Process Reference: <u>TPS51217DSC</u>	QBS Process Reference: <u>TPS53605DSQ</u>	QBS Package Reference: <u>TMUX1308QPWRQ1</u>				
AC	Autoclave 121C	96 Hours	-	3/231/0	-	3/231/0				
CDM	ESD - CDM	1500 V	3/9/0	-	-	-				
ED	Electrical Characterization	Per Datasheet Parameters	Pass	-	-	-				
ELFR	Early Life Failure Rate, 125C	48 Hours	-	-	3/2999/0	-				
HAST	Biased HAST 130C/85%RH	96 Hours	-	3/231/0	-	3/231/0				
HAST	Biased HAST, 110C/85%RH	264 Hours	-	-	3/231/0	-				
НВМ	ESD - HBM (All Pins)	4000 V	3/9/0	-	-	-				
НВМ	ESD - HBM (Bus Pins)	16000 V	3/9/0	-	-	-				
HTOL	Life Test, 125C	1000 Hours	3/231/0	-	3/231/0	-				
HTOL	Life Test, 135C	635 Hours	-	3/231/0	-	-				
HTOL	Life Test, 150C	300 Hours	-	-	-	3/231/0				
HTSL	High Temp Storage Bake 175C	500 Hours	-	-	-	3/135/0				
HTSL	High Temp Storage Bake, 170C	420 Hours	-	3/231/0	2/90/0	-				
LU	Latch-up	(Per JESD78)	1/6/0	-	-	-				
тс	Temperature Cycle - 65/150C	500 Cycles	-	3/231/0	3/231/0	3/231/0				
UHAST	Unbiased HAST 110C/85%RH	264 Hours	-	-	3/231/0	-				
WBP	Bond Pull	Wires	1/76/0	-	3/228/0	3/90/0				
WBS	Ball Bond Shear	Wires	1/76/0	-	3/228/0	3/90/0				

- QBS: Qual By Similarity

- Qual Device TRS3232EIPW (PG2.0) is qualified at LEVEL1-260C

- Preconditioning was performed for Autoclave, Unbiased HAST, THB/Biased HAST, Temperature Cycle, Thermal Shock, and HTSL, as applicable

- The following are equivalent HTOL options based on an activation energy of 0.7eV: 125C/1k Hours, 140C/480 Hours, 150C/300 Hours, and 155C/240 Hours

- The following are equivalent HTSL options based on an activation energy of 0.7eV: 150C/1k Hours, and 170C/420 Hours

- The following are equivalent Temp Cycle options per JESD47: -55C/125C/700 Cycles and -65C/150C/500 Cycles Quality and Environmental data is available at TI's external Web site: http://www.ti.com/

Green/Pb-free Status:

#### **Qualification Report**

#### Approve Date 01-Jun-2021

Qualification Results
Data Displayed as: Number of lots / Total sample size / Total failed

Туре	Test Name / Condition	Duration	Qual Device: <u>TRS3232EIDBR</u>	QBS Product Reference: <u>TRS3232EIPW</u> (PG2.0)	QBS Process Reference: TPS51217DSC	QBS Process Reference: <u>TP S53605D SQ</u>	QBS Package Reference: <u>TL1454ACDBR</u>	QBS Package Reference: <u>TPD3S714QDBQRQ1</u>
AC	Autoclave 121C	96 Hours	1/77/0	-	3/231/0	-	3/231/0	3/231/0
CDM	ESD - CDM	1500 V	1/3/0	-	-	-	-	-
ED	Electrical Characterization	Per Datasheet Parameters	Pass	Pass	-	-	-	-
ELFR	Early Life Failure Rate, 125C	48 Hours	-	-	-	3/2999/0	-	-
HAST	Biased HAST 130C/85%RH	96 Hours	-	-	3/231/0	-	-	3/231/0
HAST	Biased HAST, 110C/85%RH	264 Hours	-	-	-	3/231/0	-	-
HBM	ESD - HBM (All Pins)	4000 V	-	3/9/0	-	-	-	-
нвм	ESD - HBM (Bus Pins)	16000 V	-	3/9/0	-	-	-	-
HTOL	Life Test, 125C	1000 Hours	-	3/231/0	-	3/231/0	-	-
HTOL	Life Test, 135C	635 Hours	-	-	3/231/0	-	-	-
HTOL	Life Test, 150C	408 hours	-	-	-	-	-	3/231/0
HTSL	High Temp Storage Bake 170C	420 Hours	-	-	3/231/0	2/90/0	3/227/0	-
HTSL	High Temp Storage Bake 175C	500 hours	-	-	-	-	-	3/135/0
LU	Latch-up	(Per JESD78)	-	1/6/0	-	-	-	-
TC	Temperature Cycle, - 65/150C	500 Cycles	1/77/0	-	3/231/0	3/231/0	3/231/0	3/231/0
UHAST	Unbiased HAST 110C/85%RH	264 Hours	-	-	-	3/231/0	-	-
WBP	Bond Pull	Wires	1/76/0	1/76/0	-	3/228/0	-	3/228/0
WBS	Ball Bond Shear	Wires	1/76/0	1/76/0	-	3/228/0	-	3/90/0

- QBS: Qual By Similarity - Qual Device TRS3232EIDBR is qualified at LEVEL1-260C

- Preconditioning was performed for Autoclave, Unbiased HAST, THB/Biased HAST, Temperature Cycle, Thermal Shock, and HTSL, as applicable

- The following are equivalent HTOL options based on an activation energy of 0.7eV: 125C/1k Hours, 140C/480 Hours, 150C/300 Hours, and 155C/240 Hours

- The following are equivalent HTSL options based on an activation energy of 0.7eV: 150C/1k Hours, and 170C/420 Hours

- The following are equivalent Temp Cycle options per JESD47: -55C/125C/700 Cycles and -65C/150C/500 Cycles

Quality and Environmental data is available at TI's external Web site: http://www.ti.com/

Green/Pb-free Status:

# Qualification Report Approve Date 03-Jun-2021

#### Qualification Results

#### Data Displayed as: Number of lots / Total sample size / Total failed

Туре	Test Name / Condition	Duration	Qual Device: <u>TR\$F3232EIPWR</u>	QBS Product Reference: <u>TRSF3232EIRGT</u>	QBS Process Reference: <u>TPS51217DSC</u>	QBS Process Reference: <u>TP S53605D SQ</u>	QBS Package Reference: <u>TMUX1308QPWRQ1</u>
AC	Autoclave 121C	96 Hours	-	-	3/231/0	-	3/231/0
CDM	ESD - CDM	1500 V	1/3/0	-	-	-	-
ED	Electrical Characterization	Per Datasheet Parameters	Pass	Pass	-	-	-
ELFR	Early Life Failure Rate, 125C	48 Hours	-	-	-	3/2999/0	-
HAST	Biased HAST 130C/85%RH	96 Hours	-	-	3/231/0	-	3/231/0
HAST	Biased HAST, 110C/85%RH	264 Hours	-	-	-	3/231/0	-
нвм	ESD - HBM (All Pins)	4000 V	1/3/0	-	-	-	-
нвм	ESD - HBM (Bus Pins)	16000 V	1/3/0	-	-	-	-
HTOL	Life Test, 125C	1000 Hours	-	-	-	3/231/0	-
HTOL	Life Test, 135C	635 Hours	-	-	3/231/0	-	-
HTOL	Life Test, 150C	300 Hours	-	-	-	-	3/231/0
HTSL	High Temp Storage Bake 170C	420 Hours	-	-	3/231/0	-	-
HTSL	High Temp Storage Bake 175C	500 Hours	-	-	-	-	3/135/0
LU	Latch-up	(per JESD78)	-	1/6/0	-	-	-
тс	Temperature Cycle, -65/150C	500 Cycles	-	-	3/231/0	3/231/0	3/231/0
UHAST	Unbiased HAST 110C/85%RH	264 Hours	-	-	-	3/231/0	-
WBP	Bond Pull	Wires	1/76/0	1/76/0	-	3/228/0	3/90/0
WBS	Ball Bond Shear	Wires	1/76/0	1/76/0	-	3/228/0	3/90/0

- QBS: Qual By Similarity

- Qual Device TRSF3232EIPWR is qualified at LEVEL1-260C

- Preconditioning was performed for Autoclave, Unbiased HAST, THB/Biased HAST, Temperature Cycle, Thermal Shock, and HTSL, as applicable

- The following are equivalent HTOL options based on an activation energy of 0.7eV: 125C/1k Hours, 140C/480 Hours, 150C/300 Hours, and 155C/240 Hours

- The following are equivalent HTSL options based on an activation energy of 0.7eV: 150C/1k Hours, and 170C/420 Hours

- The following are equivalent Temp Cycle options per JESD47: -55C/125C/700 Cycles and -65C/150C/500 Cycles

Quality and Environmental data is available at TI's external Web site: http://www.ti.com/

Green/Pb-free Status:

#### Qualification Report

#### Approve Date 03-Jun-2021

				Quai	ification Result	5			
Data Displayed as: Number of lots / Total sample size / Total failed									
Туре	Test Name / Condition	Duration	Qual Device: TRSF3232EIDBR	QBS Product Reference: <u>TRSF3232EIPWR</u>	QBS Product Reference: <u>TRSF3232EIRGT</u>	QBS Process Reference: <u>TPS51217DSC</u>	QBS Process Reference: <u>TPS53605DSQ</u>	QBS Package Reference: <u>TL1454ACDBR</u>	QBS Package Reference: <u>TPD3S714QDBQRG</u>
AC	Autoclave 121C	96 hours	-	-	-	3/231/0	-	3/231/0	3/231/0
CDM	ESD - CDM	1500 V	1/3/0	-	-	-	-	-	-
ED	Electrical Characterization	Per Datasheet Parameters	Pass	Pass	Pass	-	-	-	-
ELFR	Early Life Failure Rate, 125C	48 Hours	-	-	-	-	3/2999/0	-	-
HAST	Biased HAST, 110C/85%RH	264 Hours	-	-	-	-	3/231/0	-	-
HAST	Biased HAST, 130C/85%RH	96 hours	-	-	-	3/231/0	-	-	3/231/0
нвм	ESD - HBM (All Pins)	4000 V	-	1/3/0	-	-	-	-	-
нвм	ESD - HBM (Bus Pins)	16000 V	-	1/3/0	-	-	-	-	-
HTOL	Life Test, 125C	1000 Hours	-	-	-	-	3/231/0	-	-
HTOL	Life Test, 135C	635 Hours	-	-	-	3/231/0	-	-	-
HTOL	Life Test, 150C	408 hours	-	-	-	-	-	-	3/231/0
HTSL	High Temp Storage Bake 175C	500 hours	-	-	-	-	-	-	3/135/0
HTSL	High Temp Storage Bake, 170C	420 Hours	-	-	-	3/231/0	2/90/0	3/227/0	-
LU	Latch-up	(Per JESD78)	-	-	1/6/0	-	-	-	-

# Qualification Results

Туре	Test Name / Condition	Duration	Qual Device: <u>TRSF3232EIDBR</u>	QBS Product Reference: <u>TRSF3232EIPWR</u>	QBS Product Reference: <u>TRSF3232EIRGT</u>	QBS Process Reference: <u>TPS51217DSC</u>	QBS Process Reference: <u>TPS53605DSQ</u>	QBS Package Reference: <u>TL1454ACDBR</u>	QBS Package Reference: <u>TPD3S714QDBQRQ1</u>
UHAST	Unbiased HAST 110C/85%RH	264 Hours	-	-	-	-	3/231/0	-	-
WBP	Bond Pull	Wires	1/76/0	1/76/0	1/76/0	-	3/228/0	-	3/228/0
WBS	Ball Bond Shear	Wires	1/76/0	1/76/0	1/76/0	-	3/228/0	-	3/90/0

-

-

3/231/0

3/231/0

3/231/0

- QBS: Qual By Similarity

Solderability

Temperature

Cycle, -65/150C

SD

TC

- Qual Device TRSF3232EIDBR is qualified at LEVEL1-260C

- Preconditioning was performed for Autoclave, Unbiased HAST, THB/Biased HAST, Temperature Cycle, Thermal Shock, and HTSL, as applicable

- The following are equivalent HTOL options based on an activation energy of 0.7eV: 125C/1k Hours. 140C/480 Hours. 150C/300 Hours. and 155C/240 Hours.

- The following are equivalent HTSL options based on an activation energy of 0.7eV: 150C/1k Hours, and 170C/420 Hours

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- The following are equivalent Temp Cycle options per JESD47: -55C/125C/700 Cycles and -65C/150C/500 Cycles

Quality and Environmental data is available at TI's external Web site: http://www.ti.com/

Pb-Solder

(Post 8hr

steam)

500 cycles

Green/Pb-free Status: Qualified Pb-Free (SMT) and Green

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3/45/0

3/231/0

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